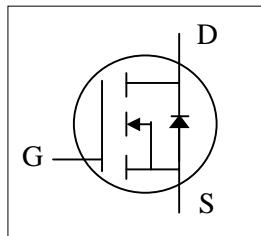




- ▼ Low Gate Charge
- ▼ Single Drive Requirement
- ▼ Fast Switching Performance

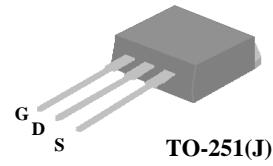
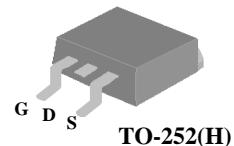


| | |
|--------------|-------|
| BV_{DSS} | 80V |
| $R_{DS(ON)}$ | 45mΩ |
| I_D | 21.3A |

Description

Advanced Power MOSFETs from APEC provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness.

The TO-252 package is widely preferred for all commercial-industrial surface mount applications and suited for low voltage applications such as DC/DC converters. The through-hole version (AP9980GJ) are available for low-profile applications.



Absolute Maximum Ratings

| Symbol | Parameter | Rating | Units |
|---------------------------|--|------------|-------|
| V_{DS} | Drain-Source Voltage | 80 | V |
| V_{GS} | Gate-Source Voltage | ± 25 | V |
| $I_D @ T_c = 25^\circ C$ | Continuous Drain Current, $V_{GS} @ 10V$ | 21.3 | A |
| $I_D @ T_c = 100^\circ C$ | Continuous Drain Current, $V_{GS} @ 10V$ | 13.4 | A |
| I_{DM} | Pulsed Drain Current ¹ | 80 | A |
| $P_D @ T_c = 25^\circ C$ | Total Power Dissipation | 41.7 | W |
| | Linear Derating Factor | 0.33 | W/°C |
| T_{STG} | Storage Temperature Range | -55 to 150 | °C |
| T_J | Operating Junction Temperature Range | -55 to 150 | °C |

Thermal Data

| Symbol | Parameter | Value | Units |
|-------------|--|-------|-------|
| R_{thj-c} | Maximum Thermal Resistance, Junction-case | 3.0 | °C/W |
| R_{thj-a} | Maximum Thermal Resistance, Junction-ambient | 110 | °C/W |

**Electrical Characteristics@T_j=25°C(unless otherwise specified)**

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Units |
|---------------------------------------|--|--|------|------|------|-------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, I _D =250uA | 80 | - | - | V |
| Δ BV _{DSS} /Δ T _j | Breakdown Voltage Temperature Coefficient | Reference to 25°C, I _D =1mA | - | 0.07 | - | V/°C |
| R _{DS(ON)} | Static Drain-Source On-Resistance ² | V _{GS} =10V, I _D =12A | - | - | 45 | mΩ |
| | | V _{GS} =4.5V, I _D =8A | - | - | 55 | mΩ |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} , I _D =250uA | 1 | - | 3 | V |
| g _{fS} | Forward Transconductance | V _{DS} =10V, I _D =12A | - | 20 | - | S |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =80V, V _{GS} =0V | - | - | 10 | uA |
| | Drain-Source Leakage Current (T _j =150°C) | V _{DS} =64V, V _{GS} =0V | - | - | 100 | uA |
| I _{GSS} | Gate-Source Leakage | V _{GS} =±25V | - | - | ±100 | nA |
| Q _g | Total Gate Charge ² | I _D =12A | - | 18 | 30 | nC |
| Q _{gs} | Gate-Source Charge | V _{DS} =64V | - | 5 | - | nC |
| Q _{gd} | Gate-Drain ("Miller") Charge | V _{GS} =4.5V | - | 11 | - | nC |
| t _{d(on)} | Turn-on Delay Time ² | V _{DS} =40V | - | 11 | - | ns |
| t _r | Rise Time | I _D =12A | - | 20 | - | ns |
| t _{d(off)} | Turn-off Delay Time | R _G =3.3Ω, V _{GS} =10V | - | 29 | - | ns |
| t _f | Fall Time | R _D =3.3Ω | - | 30 | - | ns |
| C _{iss} | Input Capacitance | V _{GS} =0V | - | 1810 | 2900 | pF |
| C _{oss} | Output Capacitance | V _{DS} =25V | - | 135 | - | pF |
| C _{rss} | Reverse Transfer Capacitance | f=1.0MHz | - | 96 | - | pF |
| R _g | Gate Resistance | f=1.0MHz | - | 1.6 | - | Ω |

Source-Drain Diode

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Units |
|-----------------|------------------------------------|---|------|------|------|-------|
| V _{SD} | Forward On Voltage ² | I _S =20A, V _{GS} =0V | - | - | 1.2 | V |
| t _{rr} | Reverse Recovery Time ² | I _S =12A, V _{GS} =0V, | - | 57 | - | ns |
| Q _{rr} | Reverse Recovery Charge | di/dt=100A/μs | - | 140 | - | nC |

Notes:

1.Pulse width limited by Max. junction temperature.

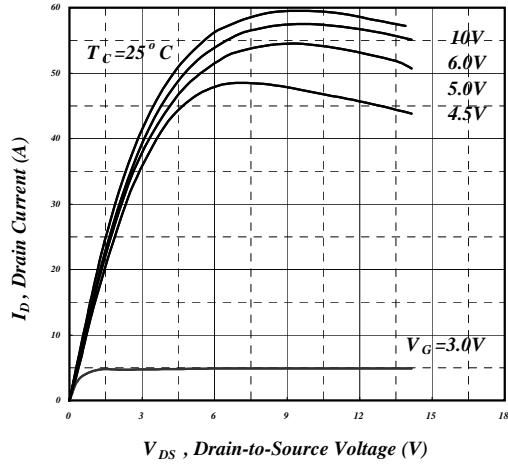
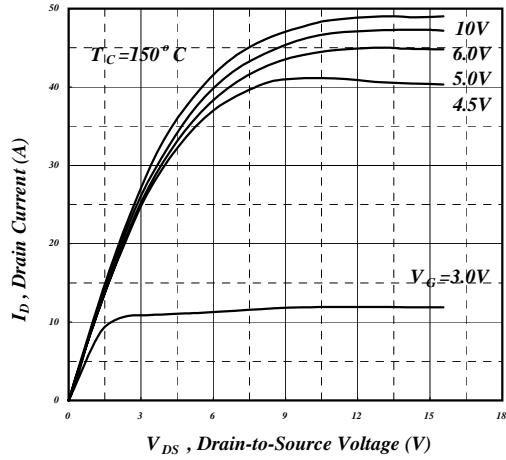
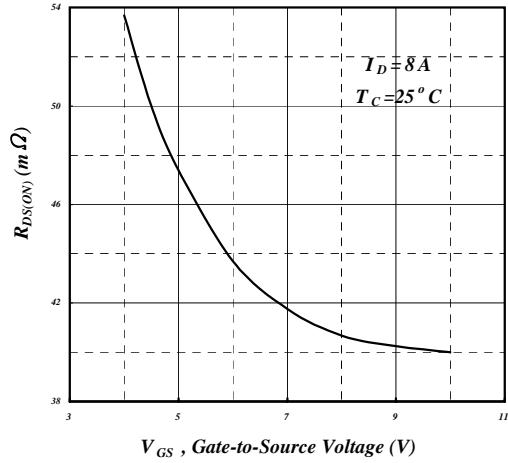
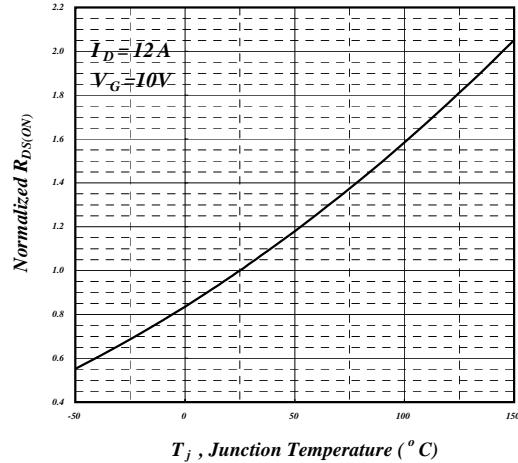
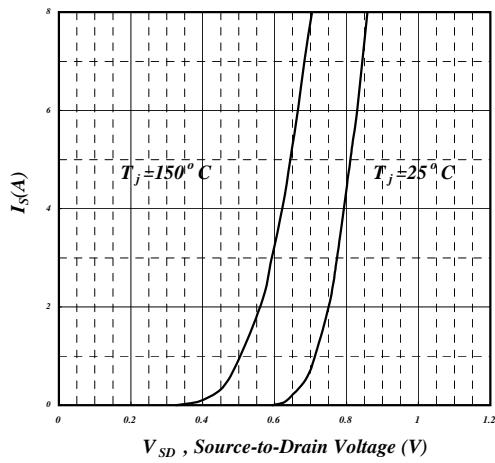
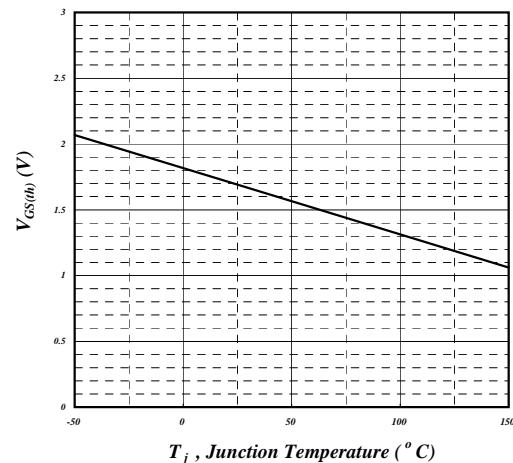
2.Pulse test

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

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APEC RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN.


Fig 1. Typical Output Characteristics

Fig 2. Typical Output Characteristics

Fig 3. On-Resistance v.s. Gate Voltage

Fig 4. Normalized On-Resistance v.s. Junction Temperature

Fig 5. Forward Characteristic of Reverse Diode

Fig 6. Gate Threshold Voltage v.s. Junction Temperature

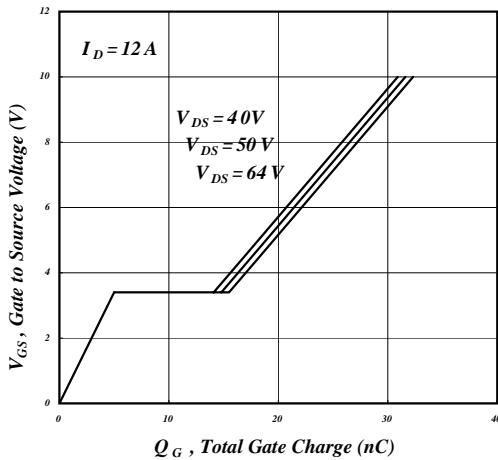


Fig 7. Gate Charge Characteristics

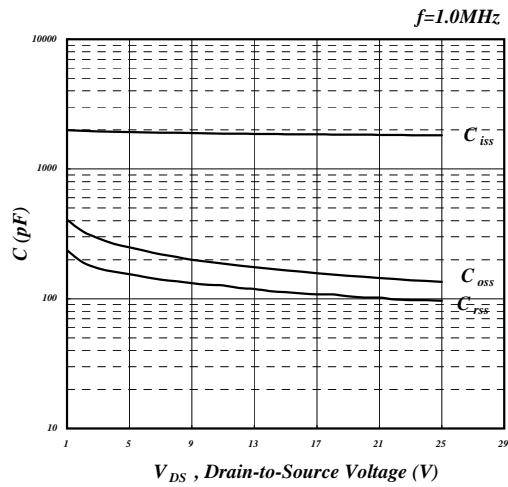


Fig 8. Typical Capacitance Characteristics

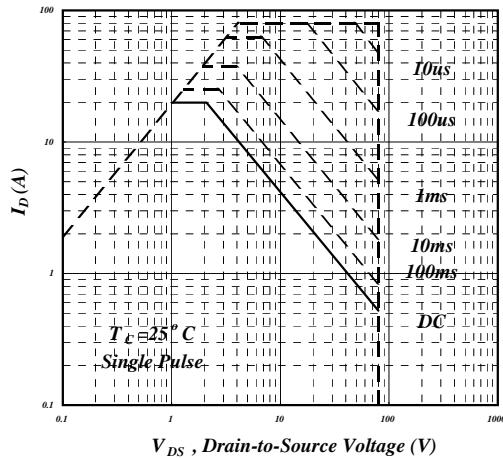


Fig 9. Maximum Safe Operating Area

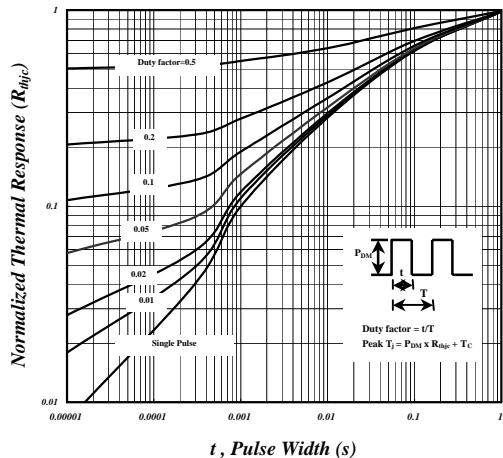


Fig 10. Effective Transient Thermal Impedance

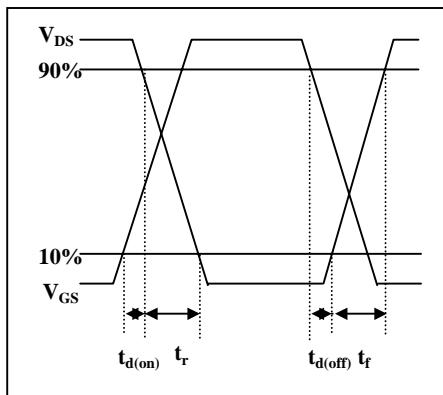


Fig 11. Switching Time Waveform

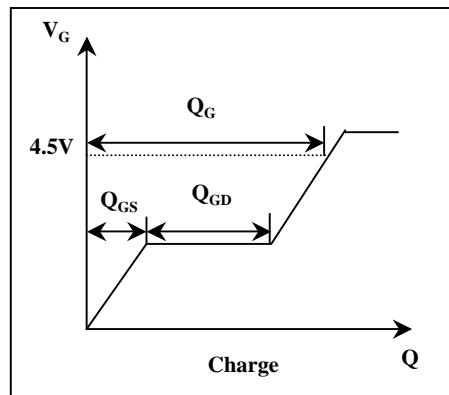
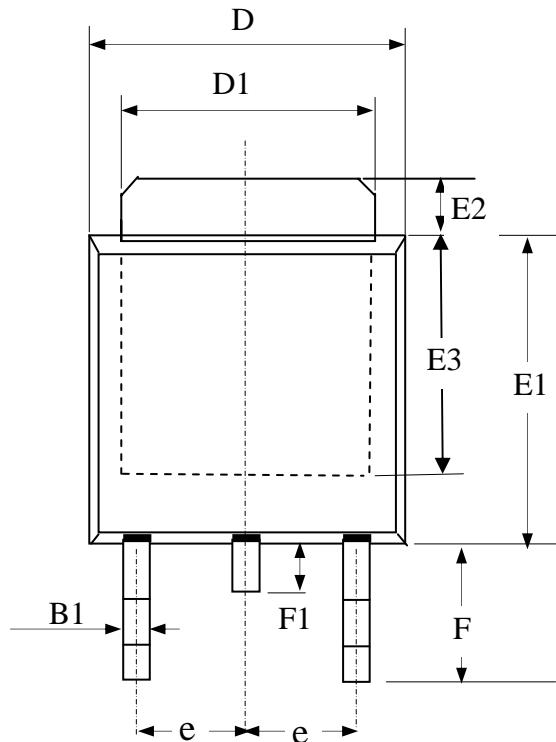


Fig 12. Gate Charge Waveform



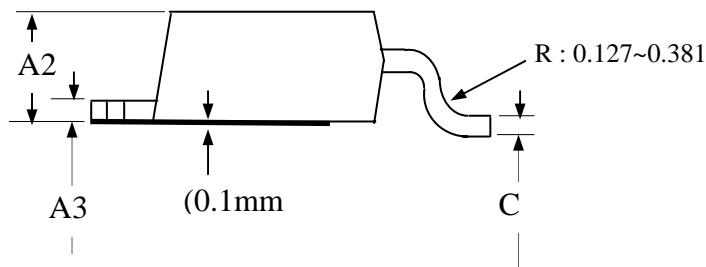
Package Outline : TO-252



| SYMBOLS | Millimeters | | |
|---------|-------------|------|------|
| | MIN | NOM | MAX |
| A2 | 1.80 | 2.30 | 2.80 |
| A3 | 0.40 | 0.50 | 0.60 |
| B1 | 0.40 | 0.70 | 1.00 |
| D | 6.00 | 6.50 | 7.00 |
| D1 | 4.80 | 5.35 | 5.90 |
| E3 | 3.50 | 4.00 | 4.50 |
| F | 2.20 | 2.63 | 3.05 |
| F1 | 0.50 | 0.85 | 1.20 |
| E1 | 5.10 | 5.70 | 6.30 |
| E2 | 0.50 | 1.10 | 1.80 |
| e | -- | 2.30 | -- |
| C | 0.35 | 0.50 | 0.65 |

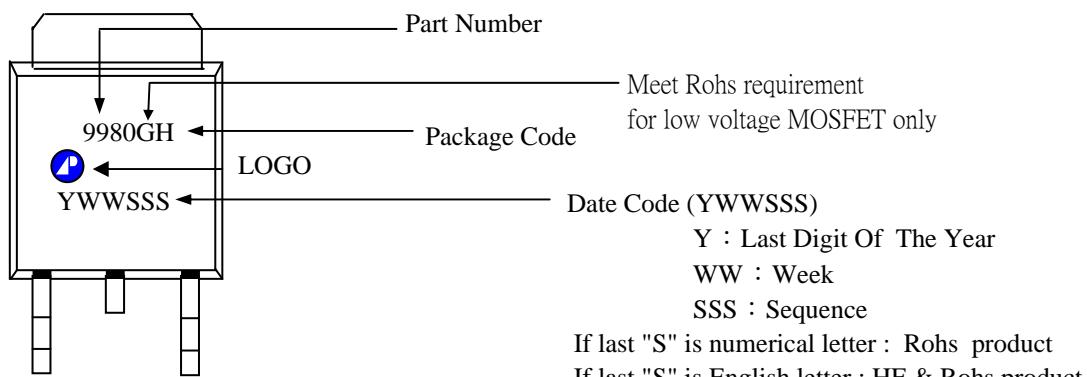
1. All Dimensions Are in Millimeters.

2. Dimension Does Not Include Mold Protrusions.



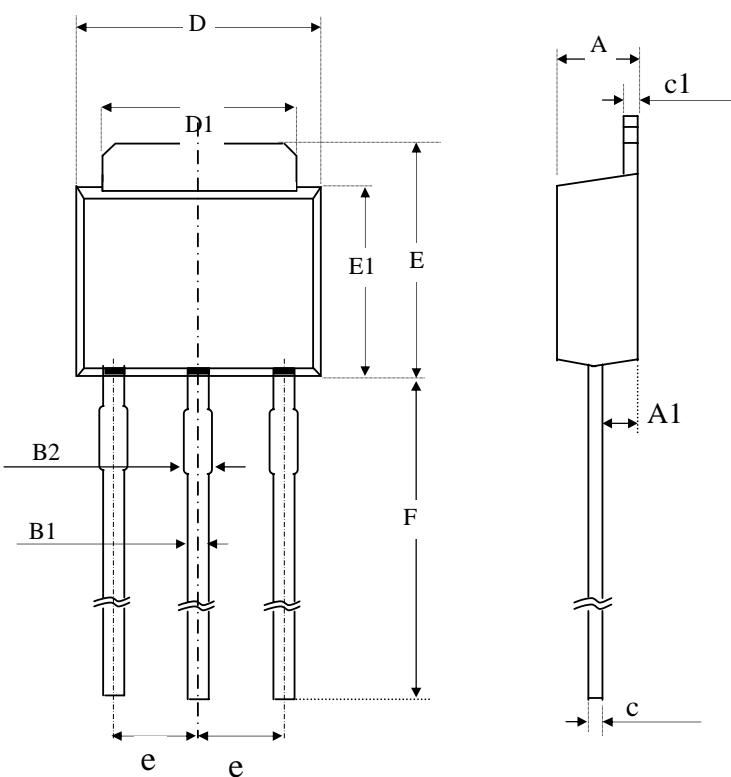
Part Marking Information & Packing : TO-252

Laser Marking





Package Outline : TO-251



| SYMBOLS | Millimeters | | |
|---------|-------------|------|------|
| | MIN | NOM | MAX |
| A | 2.20 | 2.30 | 2.40 |
| A1 | 0.90 | 1.20 | 1.50 |
| B1 | 0.50 | 0.69 | 0.88 |
| B2 | 0.60 | 0.87 | 1.14 |
| c | 0.40 | 0.50 | 0.60 |
| c1 | 0.40 | 0.50 | 0.60 |
| D | 6.40 | 6.60 | 6.80 |
| D1 | 5.20 | 5.35 | 5.50 |
| E | 6.70 | 7.00 | 7.30 |
| E1 | 5.40 | 5.80 | 6.20 |
| e | ---- | 2.30 | ---- |
| F | 5.88 | 6.84 | 7.80 |

1. All Dimensions Are in Millimeters.

2. Dimension Does Not Include Mold Protrusions.

Part Marking Information & Packing : TO-251

